Advance Technical Information

# **IXYK120N120B3 IXYX120N120B3**

High-Speed IGBT for 10-30 kHz Switching

Symbol	Test Conditions	Maximum Ratings			
V <sub>CES</sub>	T_ = 25°C to 175°C	1200	V		
V <sub>CGR</sub>	$T_{J}$ = 25°C to 175°C, $R_{GE}$ = 1M $\Omega$	1200	V		
V <sub>GES</sub>	Continuous	±20	V		
V <sub>GEM</sub>	Transient	±30	V		
I <sub>C25</sub>	$T_c = 25^{\circ}C$ (Chip Capability)	320	A		
	Terminal Current Limit	160	A		
I <sub>C110</sub>	$T_c = 110^{\circ}C$	120	A		
I <sub>CM</sub>	$T_c = 25^{\circ}C$ , 1ms	800	A		
I <sub>A</sub>	$T_{c} = 25^{\circ}C$	60	A		
E <sub>AS</sub>	$T_c = 25^{\circ}C$	2	J		
SSOA	$V_{ge} = 15V, T_{vj} = 150^{\circ}C, R_{g} = 1\Omega$	I <sub>CM</sub> = 240	A		
(RBSOA)	Clamped Inductive Load	$V_{ce} \leq V_{ces}$			
P <sub>c</sub>	$T_c = 25^{\circ}C$	1500	W		
T,		-55 +175	°C		
T <sub>JM</sub>		175	°C		
T <sub>stg</sub>		-55 +175	°C		
T	Maximum Lead Temperature for Soldering	300	°C		
	1.6 mm (0.062in.) from Case for 10s	260	°C		
M <sub>d</sub>	Mounting Torque (TO-264)	1.13/10	Nm/lb.in		
F <sub>c</sub>	Mounting Force (PLUS247)	20120 /4.527	N/lb		
Weight	TO-264P	10	g		
	PLUS247	6	g		

Symbol	Test Conditions	cteristic Values			
$(T_{J} = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max.	
BV <sub>CES</sub>	$I_c = 250\mu A, V_{GE} = 0V$	1200			V
V <sub>GE(th)</sub>	$I_{c}$ = 1mA, $V_{ce} = V_{ge}$	3.0		5.0	V
I <sub>CES</sub>	$V_{CE} = V_{CES}, V_{GE} = 0V$			25	μA
	$T_{J} = T_{J}$	150°C		1.5	mΑ
I <sub>ges</sub>	$V_{_{CE}}$ = 0V, $V_{_{GE}}$ = ±20V			±200	nA
V <sub>CE(sat)</sub>	I <sub>c</sub> = 100A, V <sub>GE</sub> = 15V, Note 1		1.8	2.2	V
- ()	$T_{\rm J} = T_{\rm J}$	150°C	2.4		V



## **Features**

- Square RBSOA
- International Standard Packages
- · Positive Thermal Coefficient of Vce(sat)
- Avalanche Rated
- High Current Handling Capability

## Advantages

- High Power Density
- Low Gate Drive Requirement

### **Applications**

- High Frequency Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

L	A15			
Tes	teristic V	eristic Values		
C Ur	hless Otherwise Specified)	Min.	Тур.	Max.
	$I_{c} = 60A, V_{ce} = 10V, Note 1$	40	70	S
)			9800	pF
}	$V_{_{CE}} = 25V, V_{_{GE}} = 0V, f = 1MHz$		567	pF
J			215	pF
)			400	nC
}	$I_{c} = I_{c110}, V_{ge} = 15V, V_{ce} = 0.5 \bullet V_{ces}$		70	nC
J			190	nC
)			30	ns
	Inductive load, T <sub>1</sub> = 25°C		54	ns
	$I_{c} = 100A, V_{GE} = 15V$		9.7	mJ
	$V_{CE} = 0.8 \cdot V_{CES}, R_{G} = 1\Omega$		340	ns
	Note 2		260	ns
)			21.5	mJ
)			29	ns
	Inductive load, T <sub>J</sub> = 150°C		55	ns
	I <sub>c</sub> = 100A, V <sub>ge</sub> = 15V		14.7	mJ
	$V_{ce} = 0.8 \bullet V_{ces}, R_{g} = 1\Omega$		420	ns
	Note 2		406	ns
J			27.9	mJ
				0.10 °C/W
			0.15	°C/W
		Test Conditions2 Unless Otherwise Specified) $l_c = 60A, V_{CE} = 10V, Note 1$ $V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$ $V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$ $l_c = I_{C110}, V_{GE} = 15V, V_{CE} = 0.5 \cdot V_{CES}$ Inductive load, $T_J = 25^{\circ}C$ $I_c = 100A, V_{GE} = 15V$ $V_{CE} = 0.8 \cdot V_{CES}, R_G = 1\Omega$ Note 2Inductive load, $T_J = 150^{\circ}C$ $I_c = 100A, V_{GE} = 15V$ $V_{CE} = 0.8 \cdot V_{CES}, R_G = 1\Omega$ Note 2Note 2	Test ConditionsCharac Min. $l_c = 60A, V_{cE} = 10V, Note 1$ 40 $l_c = 60A, V_{CE} = 10V, Note 1$ 40 $V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$ $l_c = l_{C110}, V_{GE} = 15V, V_{CE} = 0.5 \cdot V_{CES}$ Inductive load, $T_J = 25^{\circ}C$ $l_c = 100A, V_{GE} = 15V$ $V_{CE} = 0.8 \cdot V_{CES}, R_G = 1\Omega$ Note 2Inductive load, $T_J = 150^{\circ}C$ $l_c = 100A, V_{GE} = 15V$ $V_{CE} = 0.8 \cdot V_{CES}, R_G = 1\Omega$ Note 2Note 2	Image: Conditions Characteristic V. Min. Typ. $l_c = 60A, V_{ce} = 10V, Note 1$ 40 70 $l_c = 60A, V_{ce} = 10V, Note 1$ 40 70 $V_{ce} = 25V, V_{ge} = 0V, f = 1MHz$ 9800 $V_{ce} = 25V, V_{ge} = 0V, f = 1MHz$ 567 $215$ 400 $l_c = I_{c110}, V_{ge} = 15V, V_{ce} = 0.5 \cdot V_{ces}$ 70 $I_c = I_{c110}, V_{ge} = 15V, V_{ce} = 0.5 \cdot V_{ces}$ 70 $I_c = I_{010A}, V_{ge} = 15V, V_{ce} = 0.5 \cdot V_{ces}$ 70 $I_c = 100A, V_{ge} = 15V$ 9.7 $V_{ce} = 0.8 \cdot V_{ces}, R_{g} = 1\Omega$ 340   Note 2 21.5   Inductive load, $T_J = 150^{\circ}C$ 55 $I_c = 100A, V_{ge} = 15V$ 14.7 $V_{ce} = 0.8 \cdot V_{ces}, R_{g} = 1\Omega$ 420   Note 2 406   27.9 0.15

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Terminals: 1 - Gate 2,4 - Collector 3 - Emitter

CV14	INCH	IES	MILLIMETERS		
SIM	MIN MAX		MIN	MAX	
A	.190	.205	4.83	5.21	
A1	.090	.100	2,29	2.54	
A2	.075	.085	1.91	2.16	
b	.045	.055	1.14	1.40	
b2	.075	.087	1.91	2.20	
b4	.115	.126	2.92	3.20	
С	.024	.031	0.61	0.80	
D	.819	.840	20.80	21.34	
D1	.650	.690	16.51	17.53	
D2	.035	.050	0.89	1.27	
E	.620	.635	15,75	16.13	
E1	.520 .560		13.08	14.22	
е	.215	BSC	5.45 BSC		
L	.780	.810	19.81	20.57	
L1	.150	.170	3.81	4.32	
Q	.220	.244	5.59	6.20	
R	.170	.190	4.32	4.83	

### Notes:

**NVV** 

- 1. Pulse test, t  $\leq$  300µs, duty cycle, d  $\leq$  2%.
- 2. Switching times & energy losses may increase for higher  $V_{ce}$ (clamp),  $T_{J}$  or  $R_{g}$ .

# **ADVANCE TECHNICAL INFORMATION**

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the	e Right to Cl	hange Limits,	Test Conditions,	and Dimensions

IXYS MOSFETs and IGBTs are covered	4,835,592	4,931,844	5,049,961	5,237,481	6,162,665	6,404,065 B1	6,683,344	6,727,585	7,005,734 B2	7,157,338B2
by one or more of the following U.S. patents:	4,860,072	5,017,508	5,063,307	5,381,025	6,259,123 B1	6,534,343	6,710,405 B2	6,759,692	7,063,975 B2	
	4,881,106	5,034,796	5,187,117	5,486,715	6,306,728 B1	6,583,505	6,710,463	6,771,478 B2	7,071,537	



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